

# Phase transitions in two tunnel-coupled HgTe quantum wells.

# Bilayer graphene analogy and beyond.

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Sci. Rep. 6, 30755 (2016); ArXiv:1604.02423

□ Introduction: electronic states in single HgTe QWs

□ Why Double HgTe QWs? Initial motivation.

**Original results** 

□ Transition from direct to inverted band structure

□ Massless fermions at inverted band structure

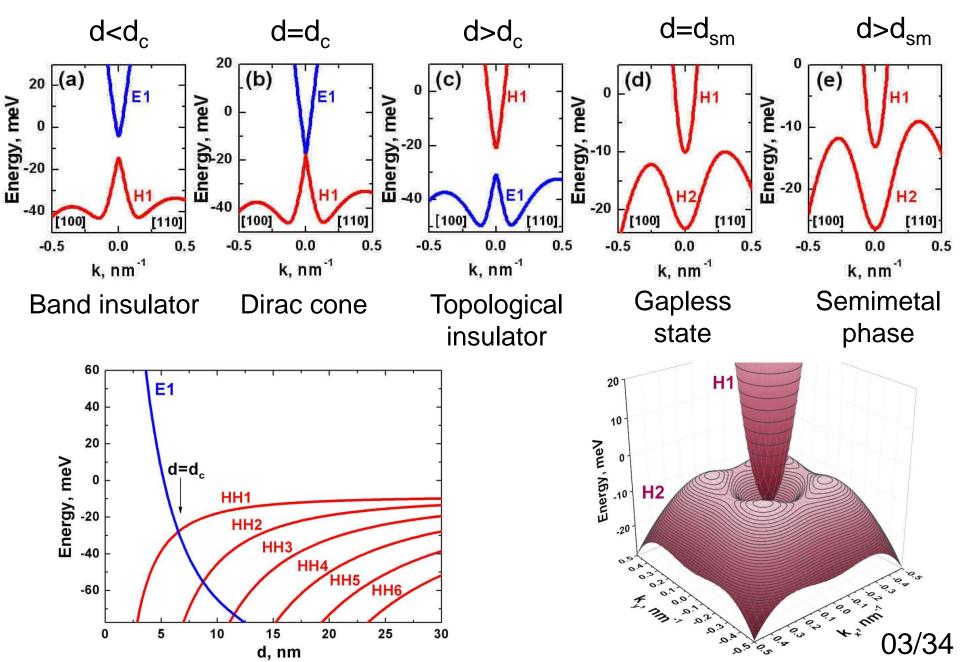
□ 'Bilayer graphene' phase in Double HgTe QW

Generalization of BHZ model. Picture of edge states

Experimental results from Montpellier

Landau Level spectroscopy of 'bilayer graphene' phase

### Phases in HgTe QWs



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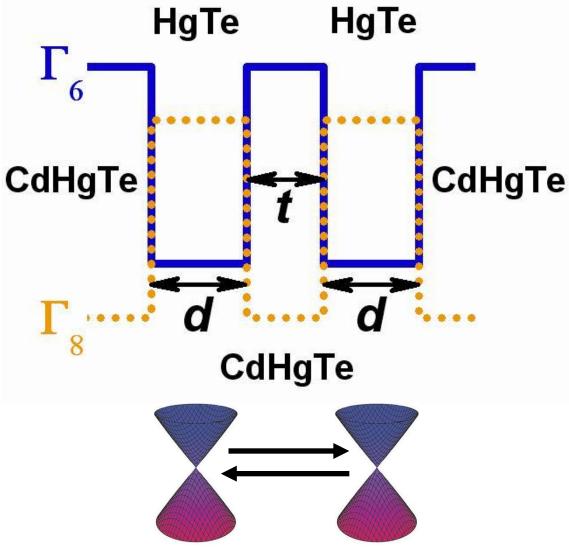
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# Initial motivation: few philosophical questions

Double HgTe QW



 Bilayer graphene?

 Fe
 Tunneling between

 edge states?

New 'topological' phases?

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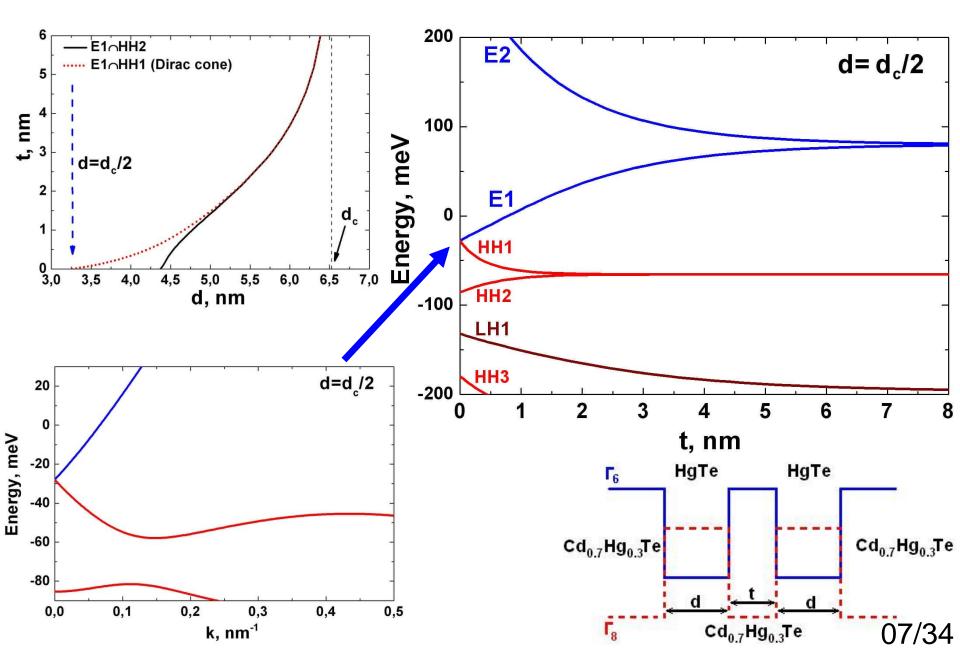
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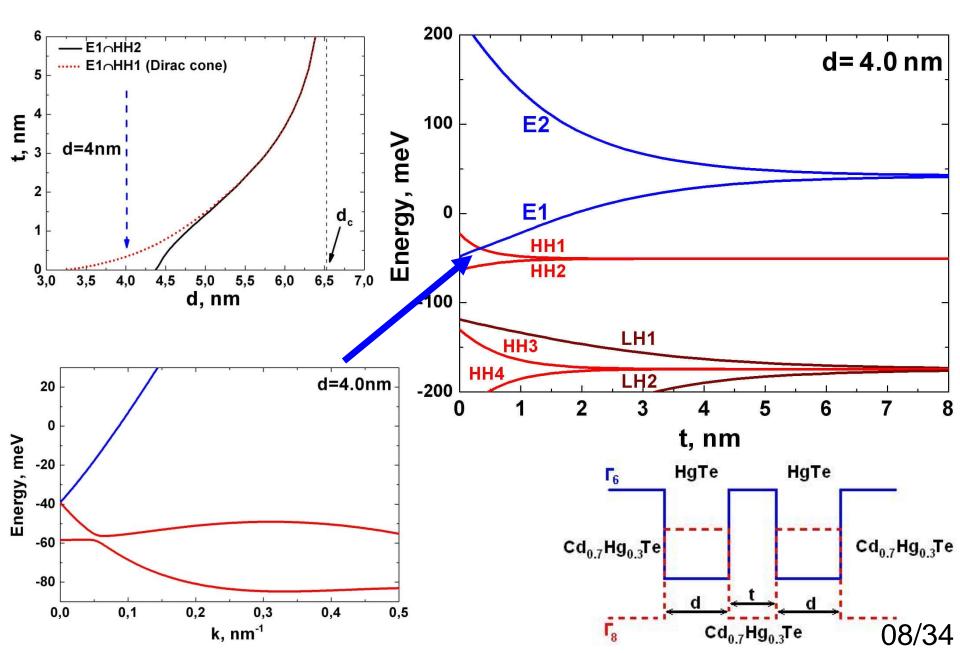
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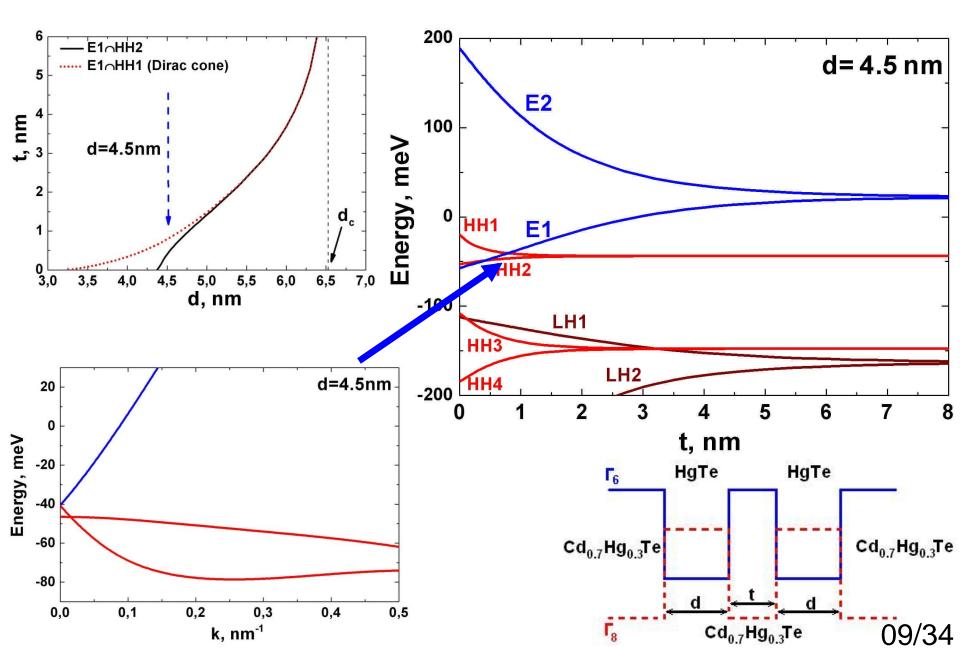
#### Band ordering at $d=d_c/2$



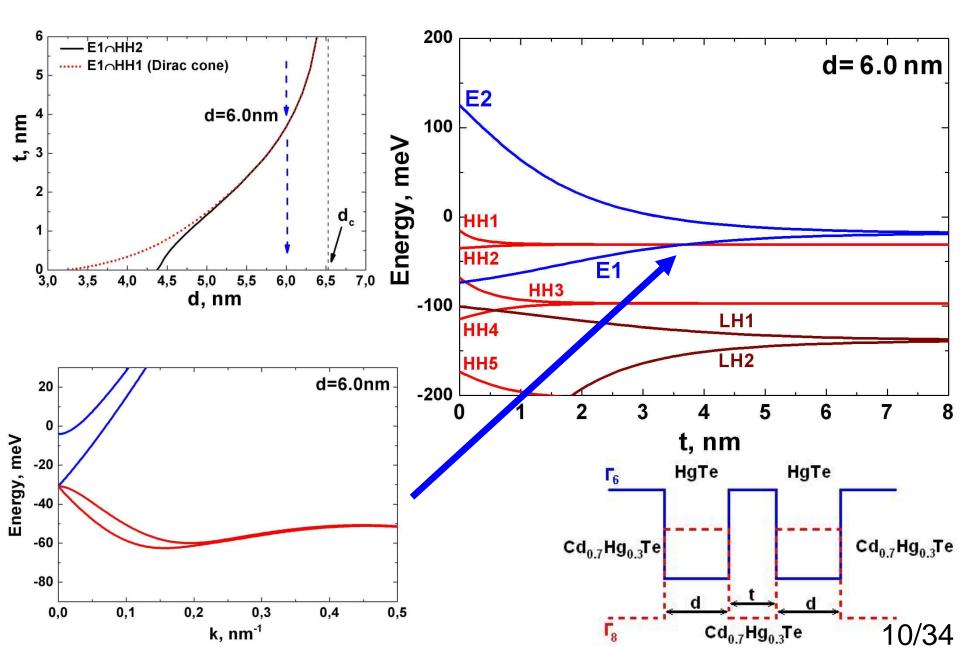
#### Band ordering at d=4.0nm



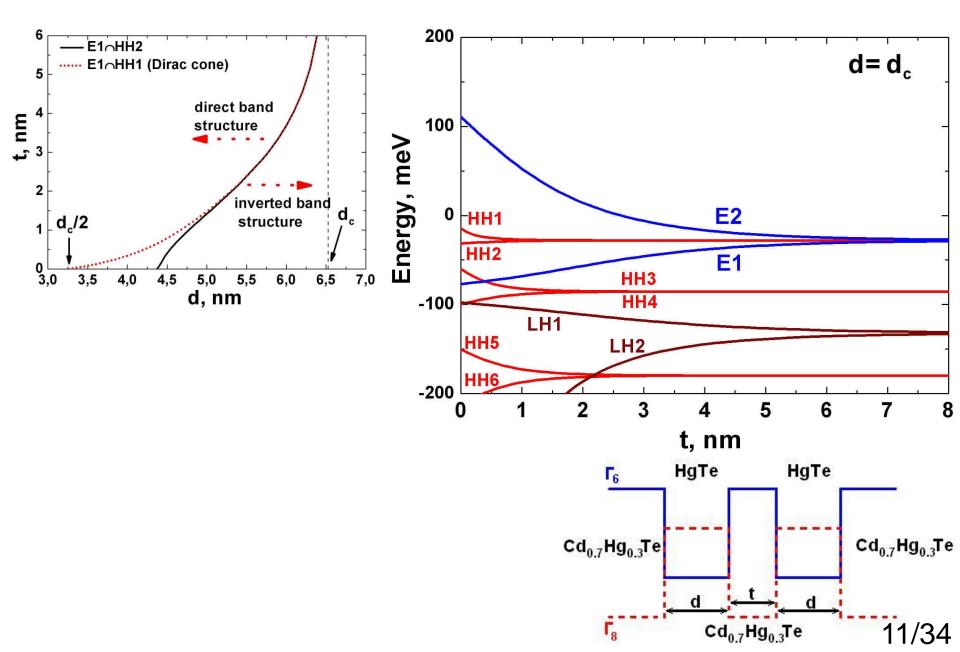
#### Band ordering at d=4.5nm



#### Band ordering at d=6.0nm



### Band ordering at d=d<sub>c</sub>



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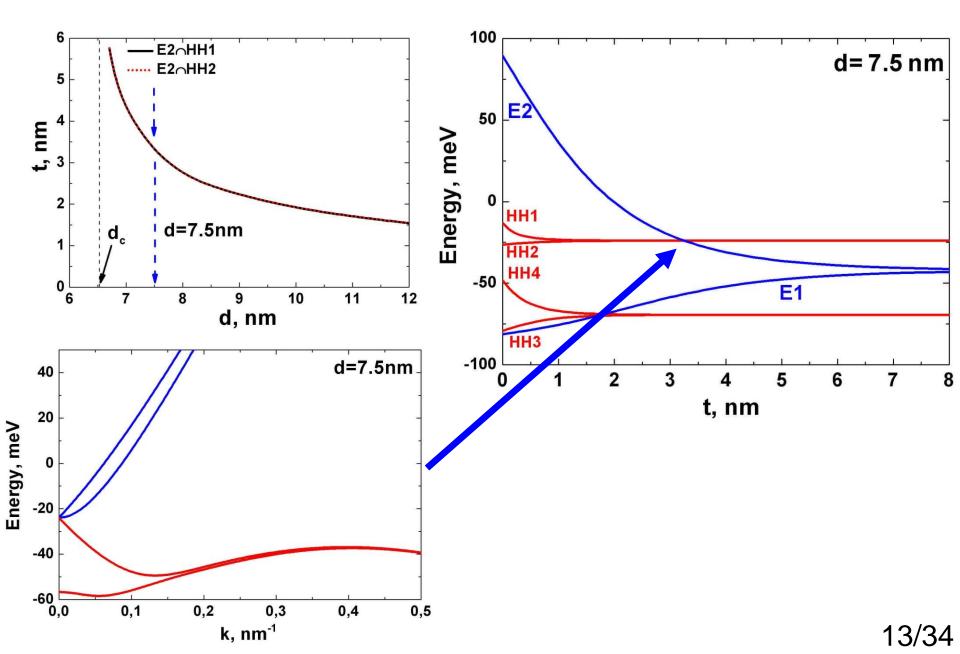
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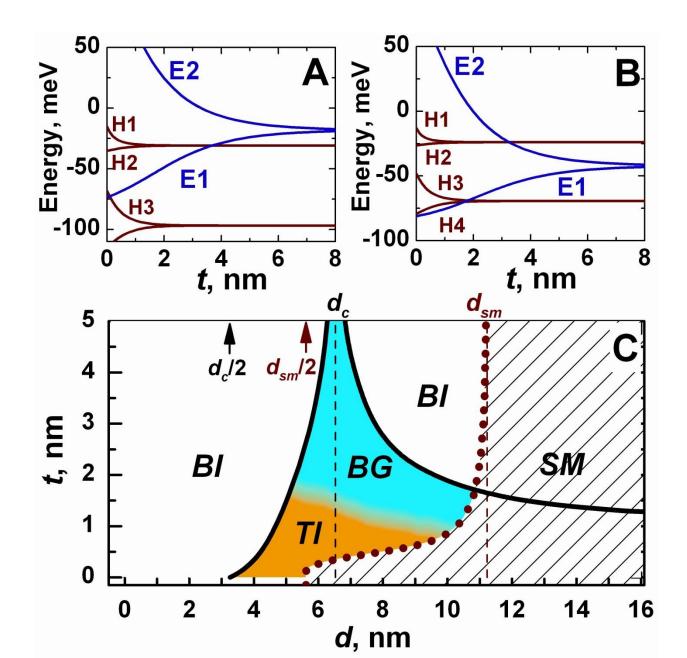
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#### Massless fermions at inverted band structure



#### Phase diagram in HgTe/Cd(Hg)Te QW



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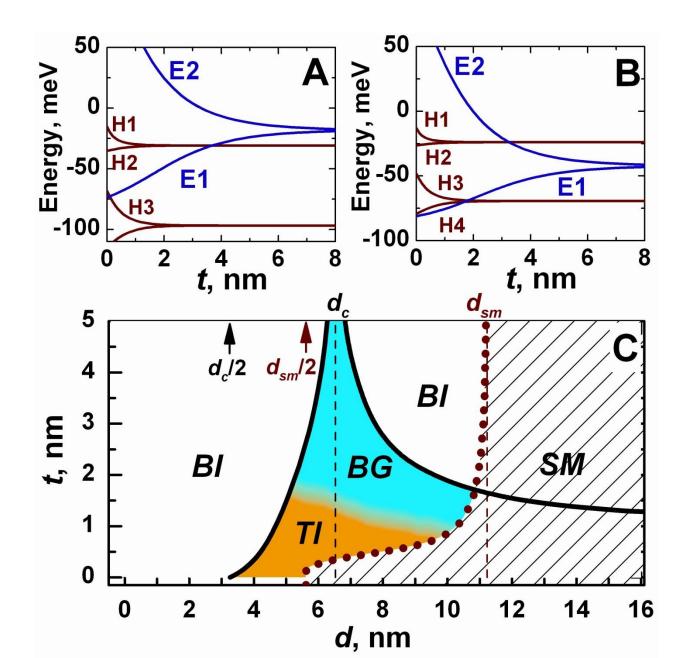
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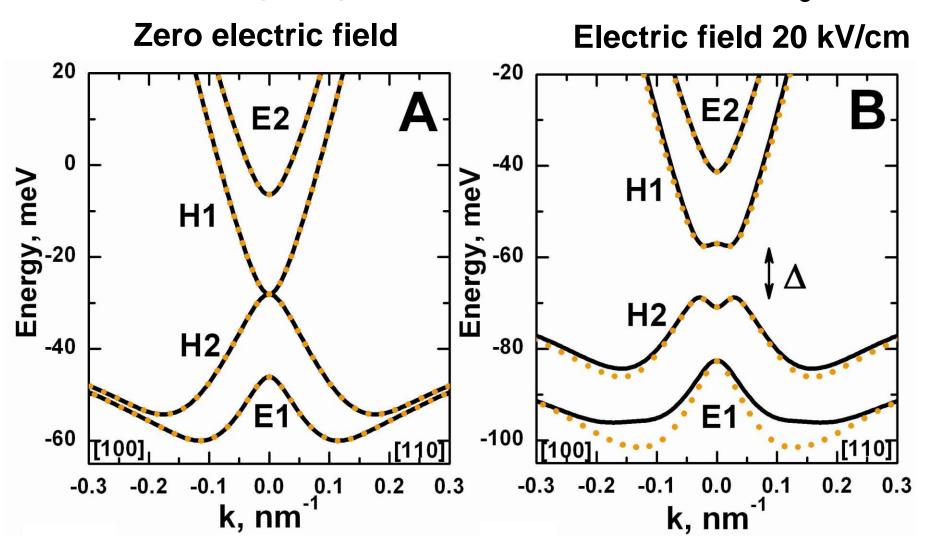
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#### Phase diagram in HgTe/Cd(Hg)Te QW



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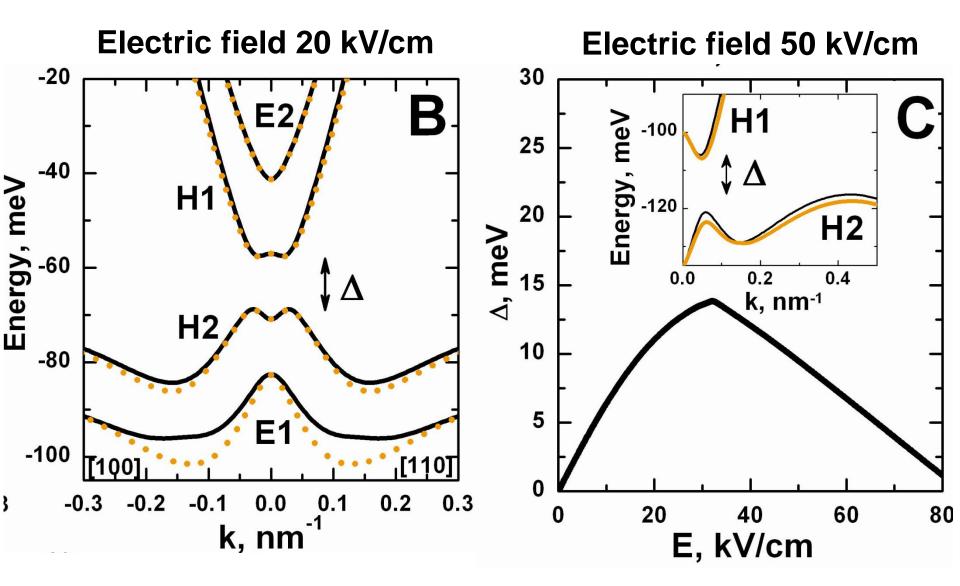
I. 'Bilayer graphene' phase at  $d = d_c$ 



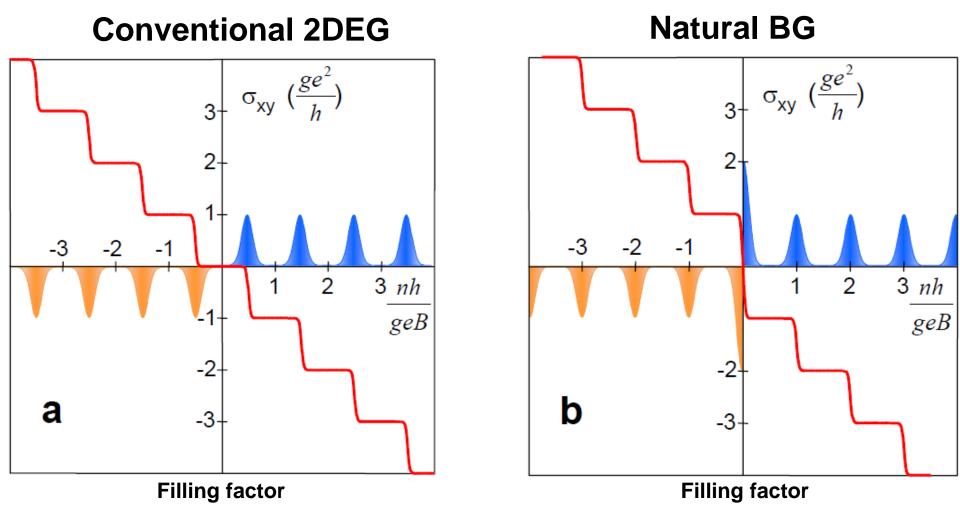
1) Spectrum consists two gapless isotropic parabolas

2) Non-zero band gap can be induced by breaking inversion symmetry between HgTe layers

#### II. 'Bilayer graphene' phase at $d = d_c$

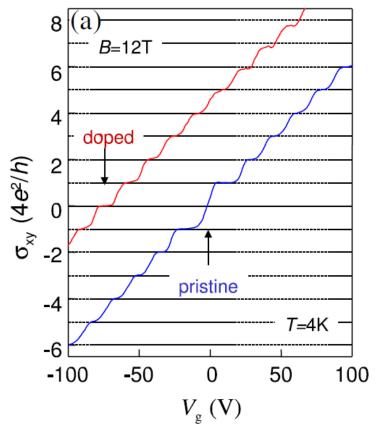


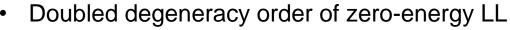
### III. 'Bilayer graphene' phase at $d = d_c$ . Unconventional quantum Hall effect.



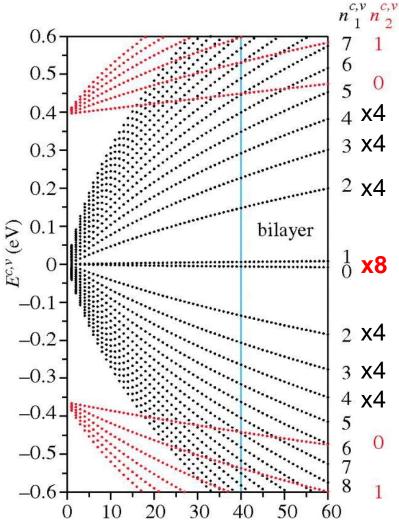
K. S. Novoselov, et al. Nature Physics 2, 177 (2006).

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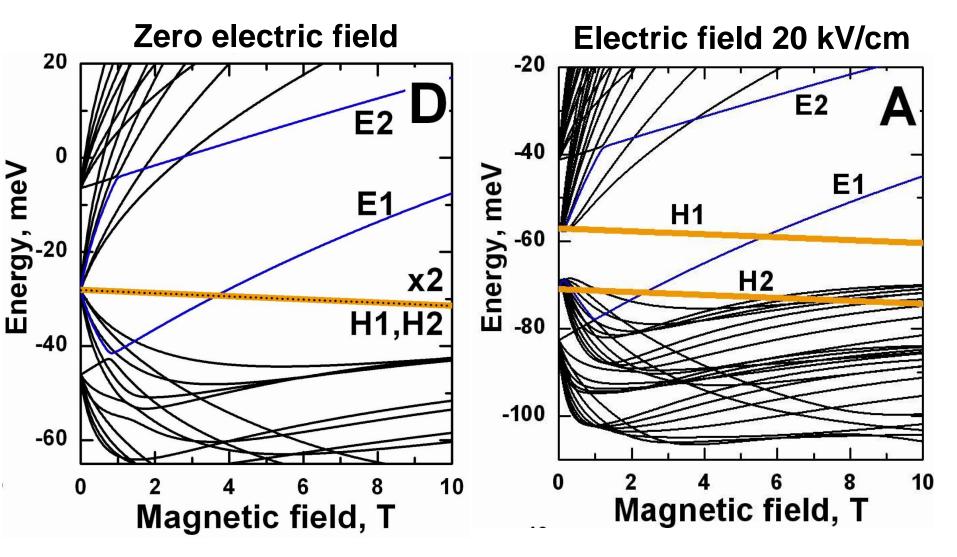
- SIA destroys unconventional QHE
- E. V. Castro *et al. Phys. Rev. Lett.* **99**, 216802 (2007).
- E. McCann, V. I. Fal'ko. Phys. Rev. Lett. 96, 086805 (2006).



 $B_0(T)$ 

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# III. 'Bilayer graphene' phase at $d = d_c$ . Unconventional quantum Hall effect.



 Prediction unconventional QHE in double HgTe QWs as in natural BG 21/34

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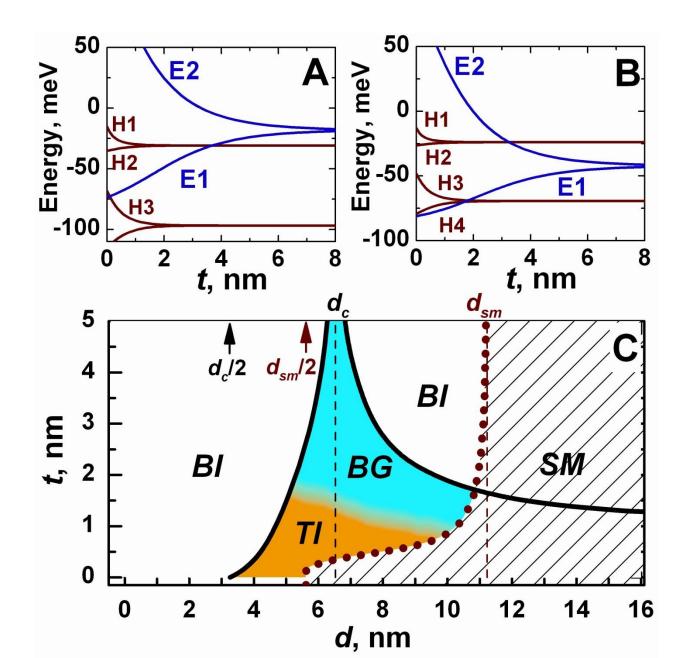
General General Sector Sector

Generalization of BHZ model. Picture of edge states

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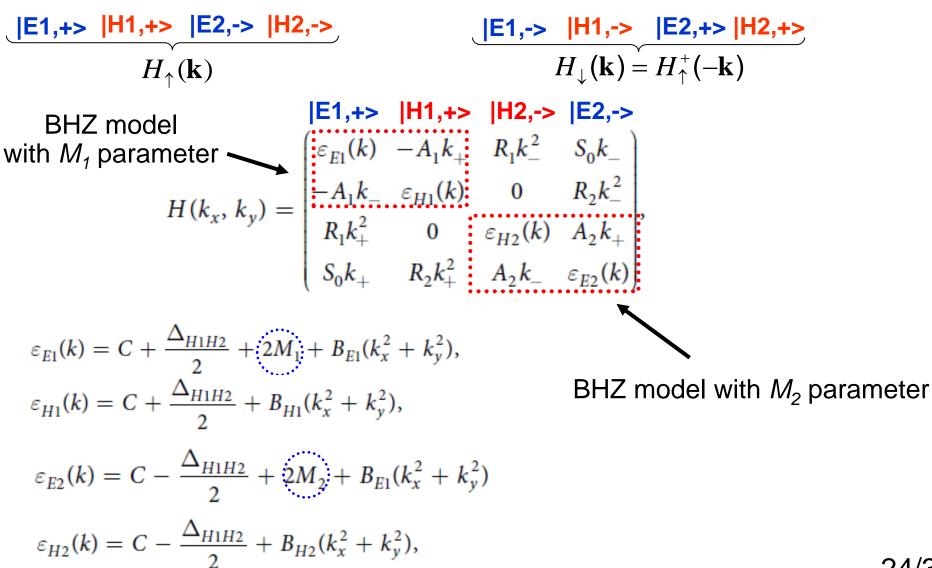
#### Phase diagram in HgTe/Cd(Hg)Te QW



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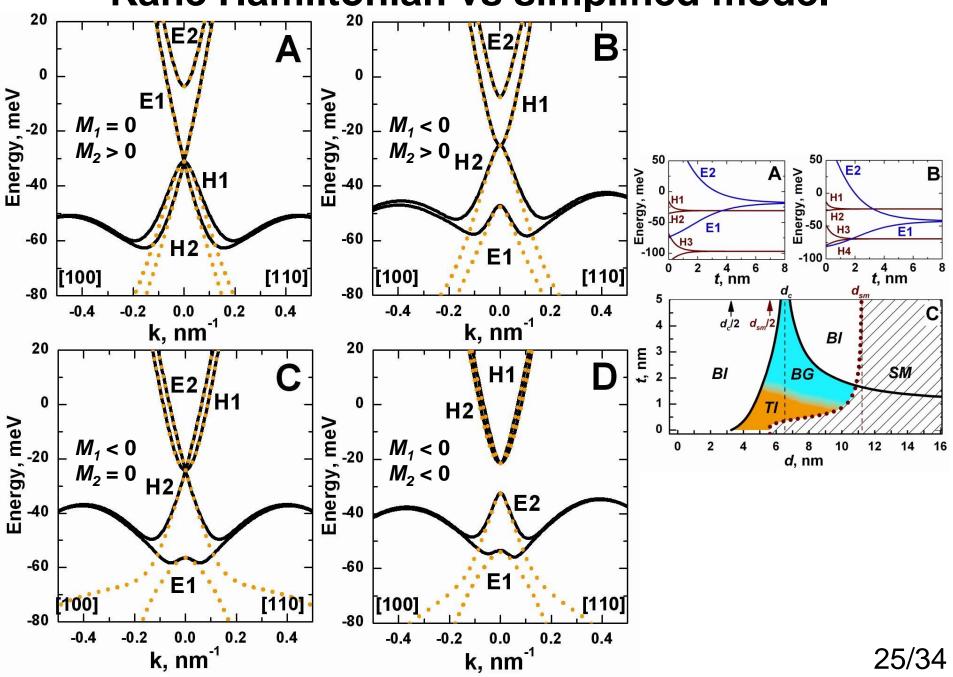
#### Generalization of BHZ model. Straightforward derivation from the Kane Hamiltonian

Kramer's partners

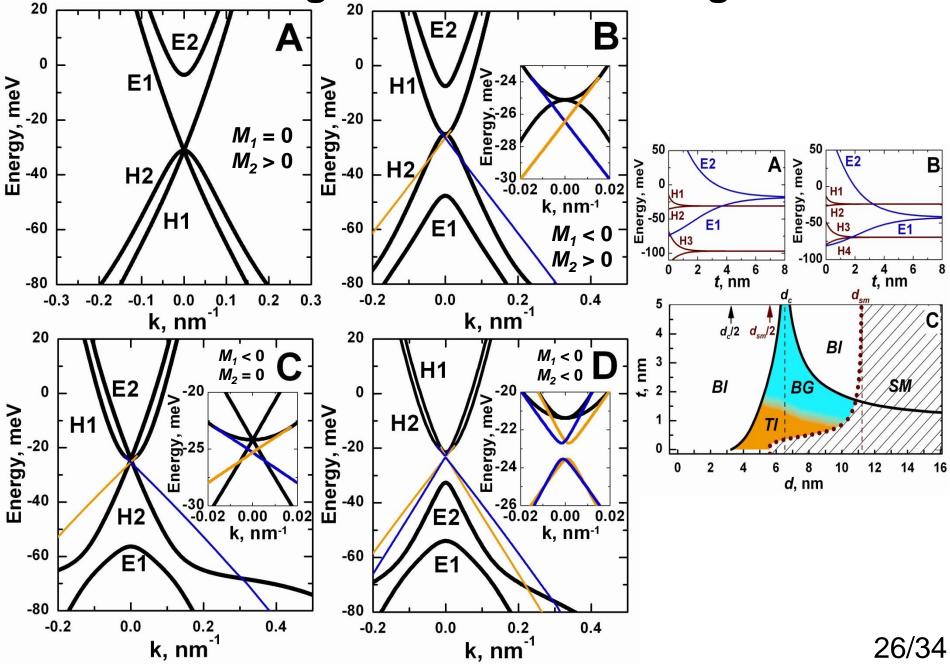


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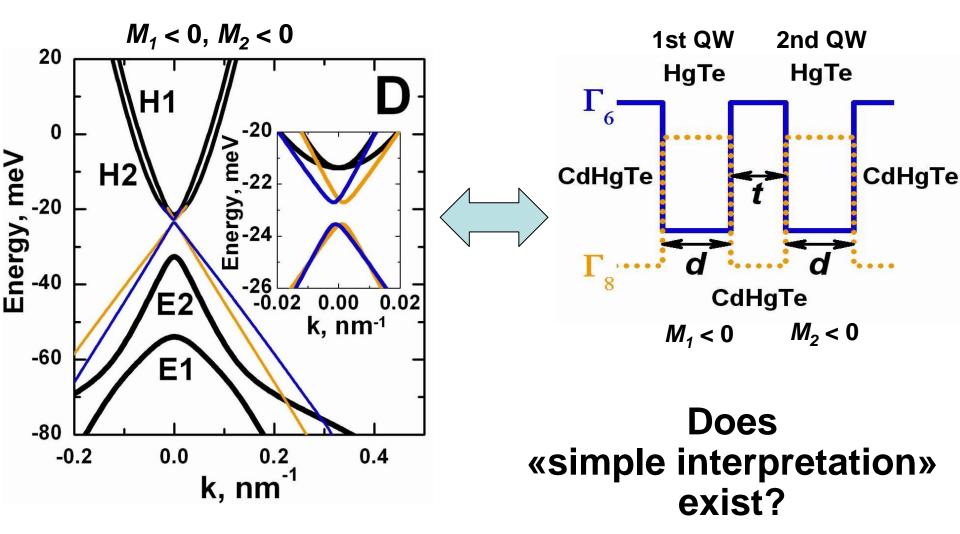
#### Kane Hamiltonian vs simplified model



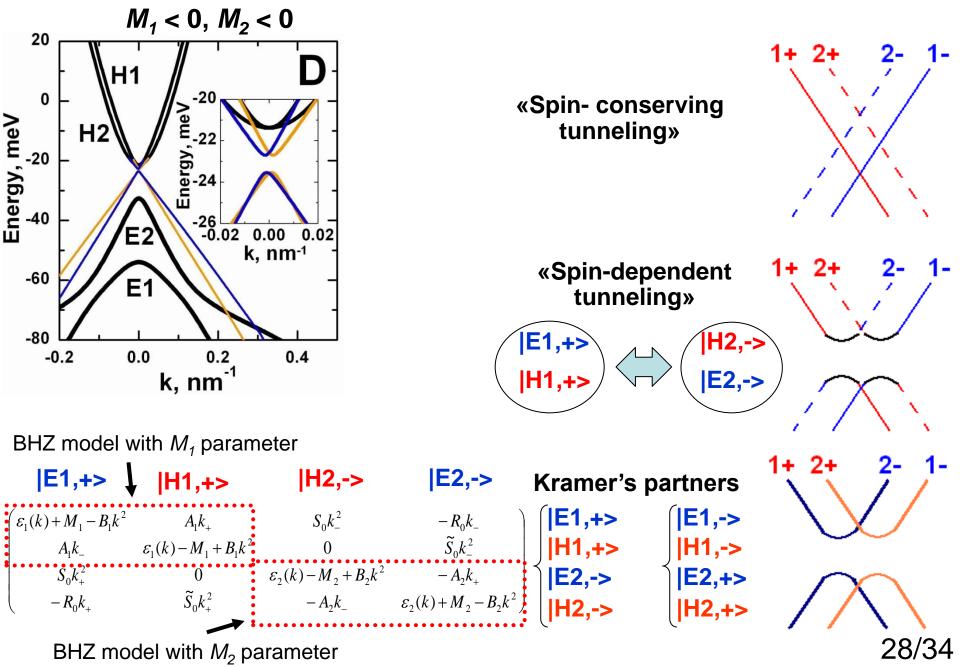




#### Band gap in the case of «double inversion»



#### Band gap in the case of «double inversion»



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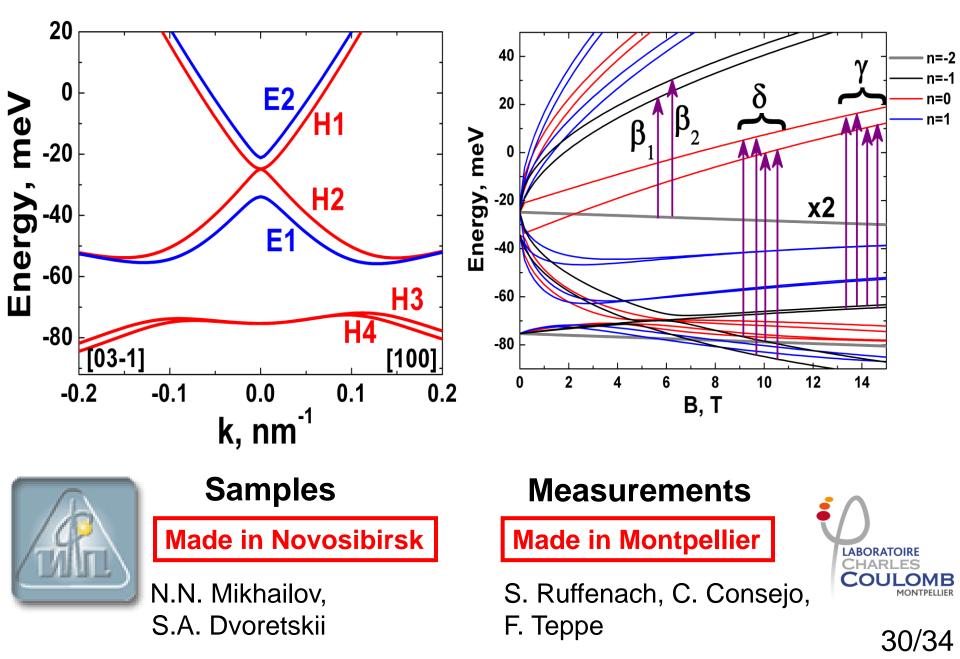
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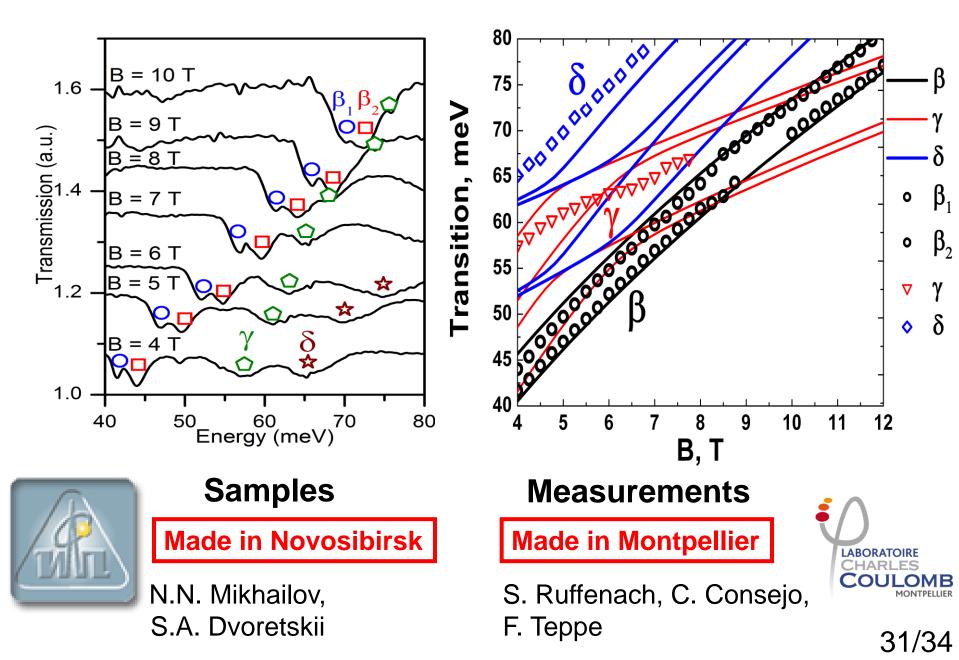
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#### Landau Level spectroscopy of 'bilayer graphene'



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# Acknowledgements



#### V.I. Gavrilenko

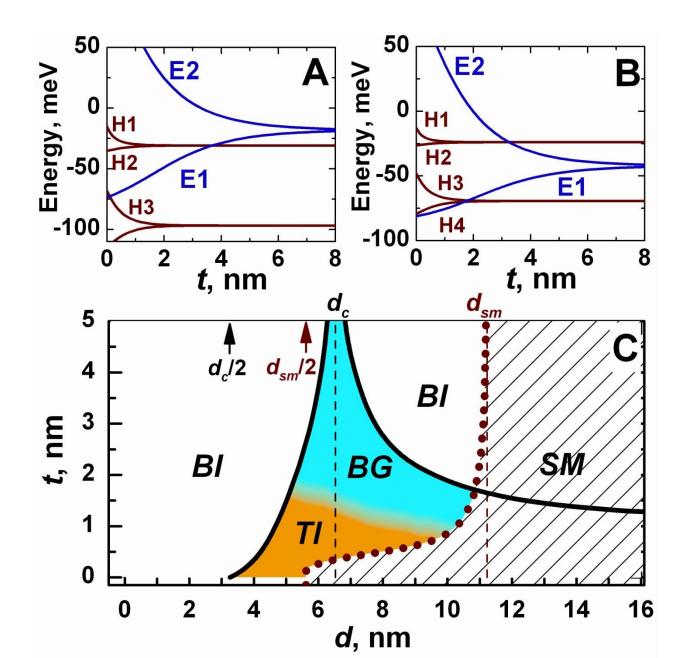
Laboratoire Charles Coulomb, UMR 5221 Montpellier



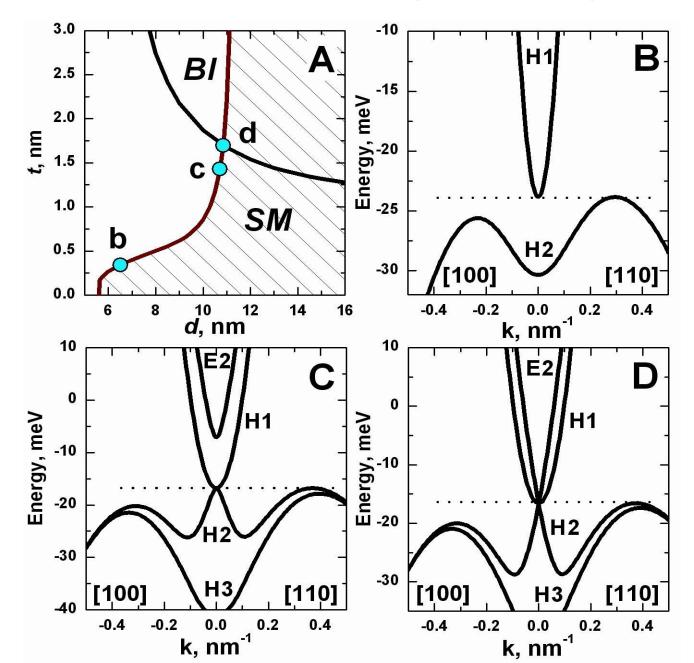
#### A. Fedorenko, T. Louvet, D. Carpentier Physics Laboratory at ENS de *Lyon*

# Thank you for your attention!

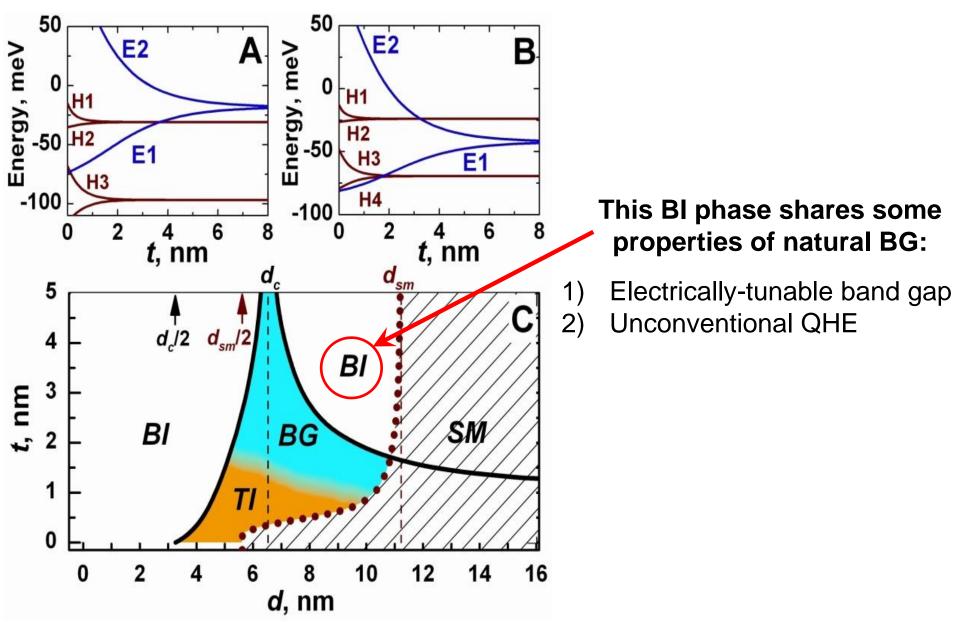
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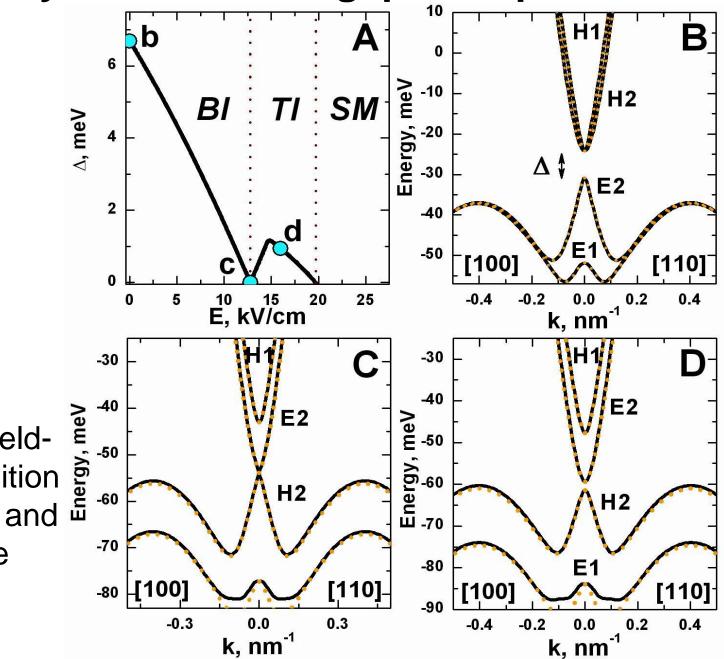
#### Semimetal phase in HgTe/Cd(Hg)Te QW



# Specific band insulator phase at inverted band structure QWs

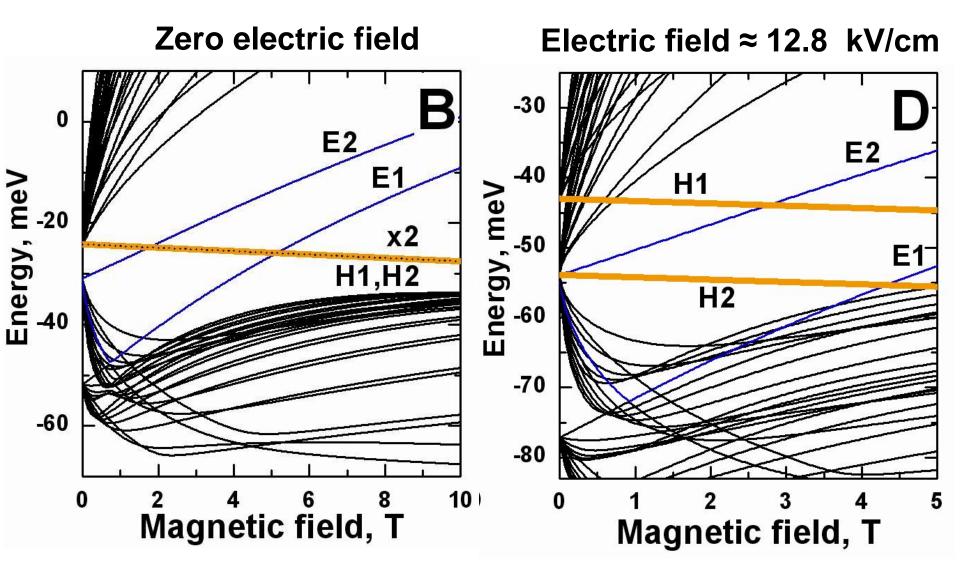


#### Electrically-tunable band gap in BI phase at d>d<sub>c</sub>



Electrical-fielddriven transition between BI and TI phase

## Unconventional QHE in BI phase at d>d<sub>c</sub>



- Doubled degeneracy order of zero-mode LL
- SIA destroys unconventional QHE